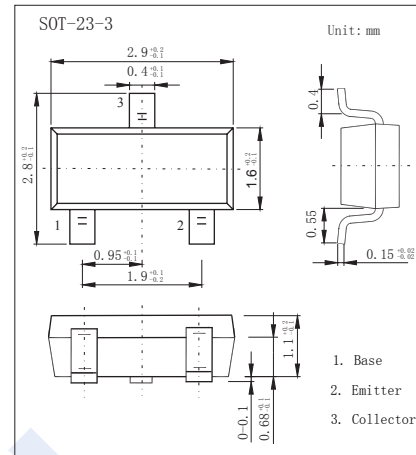


PNP Transistors

2SA1330-HF

■ Features

- High DC current gain.
- High voltage.
- Complementary to 2SC3360-HF
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage	V_{CB0}	-200	V
Collector-emitter voltage	V_{CE0}	-200	V
Emitter-base voltage	V_{EB0}	-5	V
Collector current	I_c	-100	mA
Total power dissipation	P_T	200	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V_{CB0}	$I_c = -100 \mu\text{A}$, $I_E = 0$	-200			V
Collector- emitter breakdown voltage	V_{CE0}	$I_c = -1 \text{ mA}$, $I_B = 0$	-200			
Emitter - base breakdown voltage	V_{EB0}	$I_E = -100 \mu\text{A}$, $I_c = 0$	-5			
Collector-base cut-off current	I_{CB0}	$V_{CB} = -200 \text{ V}$, $I_E = 0$			-100	nA
Emitter cut-off current	I_{EB0}	$V_{EB} = -5 \text{ V}$, $I_c = 0$			-100	
Collector-emitter saturation voltage *	$V_{CE(sat)}$	$I_c = -50 \text{ mA}$, $I_B = -5 \text{ mA}$		-0.21	-0.3	V
Base - emitter saturation voltage *	$V_{BE(sat)}$	$I_c = -50 \text{ mA}$, $I_B = -5 \text{ mA}$		-0.8	-1.2	
Base - emitter voltage *	V_{BE}	$V_{CE} = -10 \text{ V}$, $I_c = -10 \text{ mA}$	-0.6	-0.65	-0.7	
DC current gain *	$h_{FE(1)}$	$V_{CE} = -10 \text{ V}$, $I_c = -10 \text{ mA}$	90	200	450	
	$h_{FE(2)}$	$V_{CE} = -10 \text{ V}$, $I_c = -50 \text{ mA}$	50	195		
Turn-on time	t_r	$V_{CC} = -10 \text{ V}$, $V_{BE(off)} = 2.5 \text{ V}$ $I_c = -10 \text{ mA}$, $I_{B1} = I_{B2} = -1.0 \text{ mA}$		0.16		us
Storage time	t_s			1.3		
Turn-off time	t_{off}			0.18		
Collector output capacitance	C_{ob}	$V_{CB} = -30 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$		3.6		pF
Transition frequency	f_T	$V_{CE} = -10 \text{ V}$, $I_E = 10 \text{ mA}$		120		MHz

* Pulse test: $t_p \leq 350 \mu\text{s}$; duty cycle ≤ 0.02 .

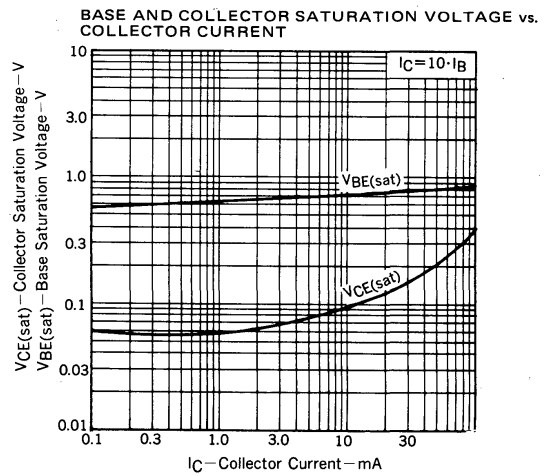
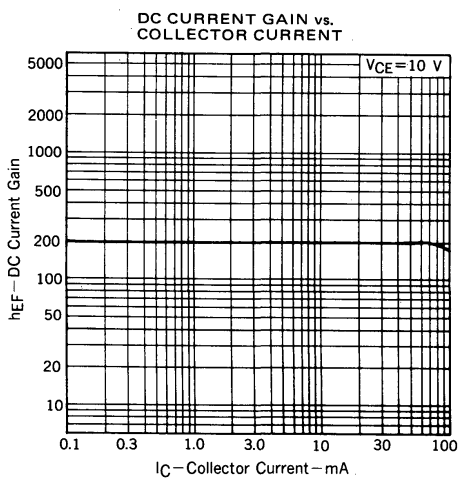
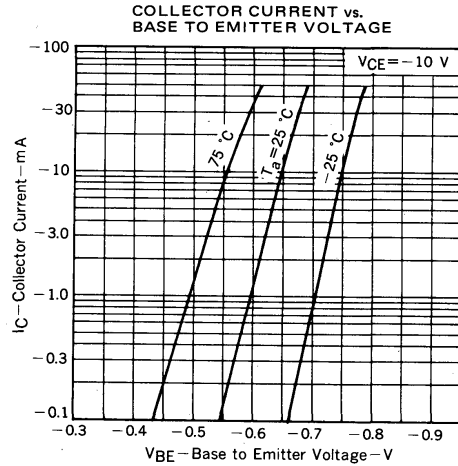
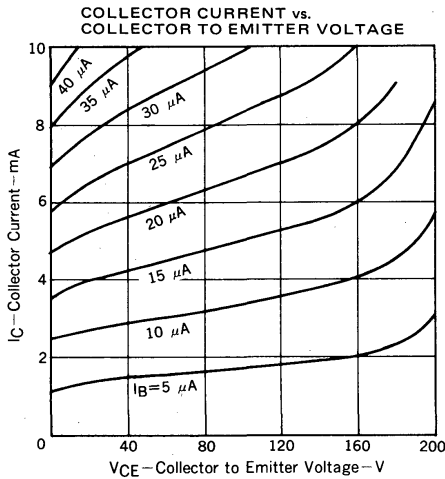
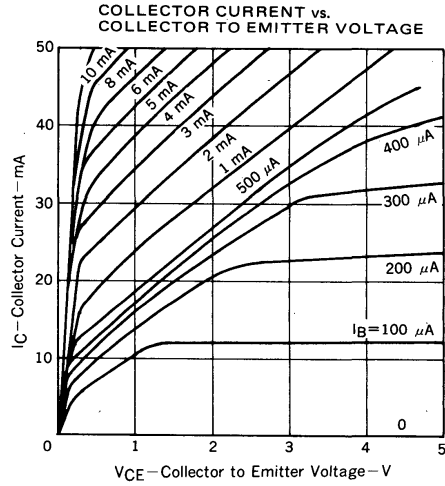
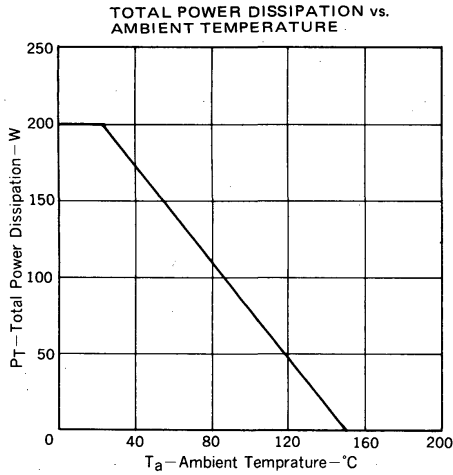
■ Classification of $h_{FE(1)}$

Type	2SA1330-O5-HF	2SA1330-O6-HF	2SA1330-O7-HF
Range	90-180	135-270	200-450
Marking	O5 _F	O6 _F	O7 _F

PNP Transistors

2SA1330-HF

■ Typical Characteristics



PNP Transistors

2SA1330-HF

■ Typical Characteristics

